

isc Silicon NPN Power Transistor

2SC3885

DESCRIPTION

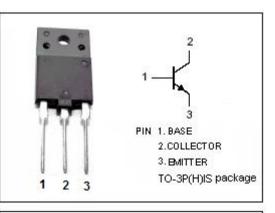
- High Breakdown Voltage
- : V_{CBO}= 1400V (Min)
- High Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

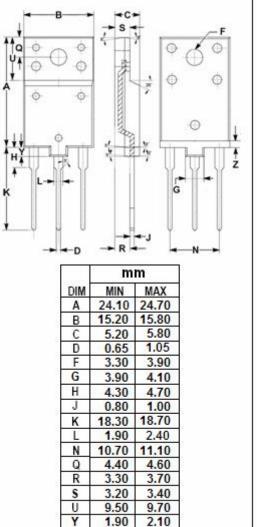
APPLICATIONS

- Horizontal deflection output for high resolution display.
- High speed switching regulator output applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)					
SYMBOL	PARAMETER	VALUE	UNIT		
V _{CBO}	Collector-Base Voltage	1400	v		
V _{CEO}	Collector-Emitter Voltage	600	V		
V _{EBO}	Emitter-Base Voltage	5	V		
Ic	Collector Current- Continuous	7	A		
Ісм	Collector Current- Peak	14	А		
lв	Base Current- Continuous	3.5	A		
Pc	Collector Power Dissipation @ Tc=25℃	50	W		
TJ	Junction Temperature	150	°C		
T _{stg}	Storage Temperature Range	-55~150	°C		

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)





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1.40

1.60



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ELECTRICAL CHARACTERISTICS

$T_{c}\text{=}25^{\circ}\!\!\!C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 5mA; I _B = 0	600			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 1.2A			5.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 5A; I _B = 1.2A			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 1400V; I _E = 0			1.0	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			10	μA
h _{FE}	DC Current Gain	I _C = 1A; V _{CE} = 5V	8			
f⊤	Current-Gain—Bandwidth Product	I _C = 0.1A; V _{CE} = 10V		3		MHz
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} = 1.0MHz		210		pF

Switching Times , Resistive load

t _{stg}	Storage Time	I _{CP} = 5A, I _{B1} = 1A; I _{B2} = -2A; R _L = 40 Ω	:	2.5	μ S
tr	Fall Time		C	0.15	μ S

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